

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

First Named Inventor: John P. Snyder

Application No.: 10/796,514

No.:

Filing Date: 03/09/2004

Title: **TRANSISTOR HAVING HIGH DIELECTRIC GATE INSULATING LAYER AND SOURCE AND DRAIN FORMING SCHOTTKY CONTACT WITH SUBSTRATE**



Confirmation No.: 1961

Examiner: Kim, Su C

Group Art Unit: 2823

**TRANSMITTAL LETTER**

Mail Stop AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

I hereby certify that this document is being sent via First Class U.S. mail addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on this 13 day of November, 2007.

*David J. King*

(Signature)

Dear Sir:

The following documents are enclosed in connection with the above-referenced patent application:

1. Response After Final (14 pages);
2. Petition for Extension of Period for Response (1 page);
3. Credit Card Payment Form in the amount of \$230 to cover the two-month extension of time fee (1 page); and
4. Return Receipt Postcard

Respectfully submitted,

Date: 11/13/2007

By: *David J. King*

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